



车规级SPI NAND Flash

- ◆ 满足AEC-Q100 Grade2 标准
- ◆ 3V/1.8V SPI NAND Flash系列
- ◆ 容量1Gb~4Gb
- ◆ 支持PPAP
- ◆ 支持长期供货 (PLP)
- ◆ 以0ppm为目标, 坚持持续改善
- ◆ 工作温度范围: -40°C~105°C
- ◆ WSON8 8x6mm 封装
- ◆ 内置ECC



3V/1.8V



Internal ECC



1Gb~4Gb



-40°C~105°C

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Voltage	Density	Part No.	Frequency	I/O Bus	Packages
2.7V-3.6V	1Gb	GD5F1GQ5UE	133MHz	x1/x2/x4	WSON8 8x6mm
2.7V-3.6V	1Gb	GD5F1GM7UE	133MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)
2.7V-3.6V	2Gb	GD5F2GQ5UE	104MHz	x1/x2/x4	WSON8 8x6mm
2.7V-3.6V	2Gb	GD5F2GM7UE	133MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)
2.7V-3.6V	4Gb	GD5F4GQ6UE	104MHz	x1/x2/x4	WSON8 8x6mm
2.7V-3.6V	4Gb	GD5F4GM8UE	133MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)
1.7V-2.0V	1Gb	GD5F1GQ5RE	104MHz	x1/x2/x4	WSON8 8x6mm
1.7V-2.0V	1Gb	GD5F1GM7RE	104MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)
1.7V-2.0V	2Gb	GD5F2GQ5RE	80MHz	x1/x2/x4	WSON8 8x6mm
1.7V-2.0V	2Gb	GD5F2GM7RE	104MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)
1.7V-2.0V	4Gb	GD5F4GQ6RE	80MHz	x1/x2/x4	WSON8 8x6mm
1.7V-2.0V	4Gb	GD5F4GM8RE	104MHz	x1/x2/x4	WSON8 8x6mm/TFBGA24 8x6mm(5x5 ball array)

